



# T10XB Series (SIP)

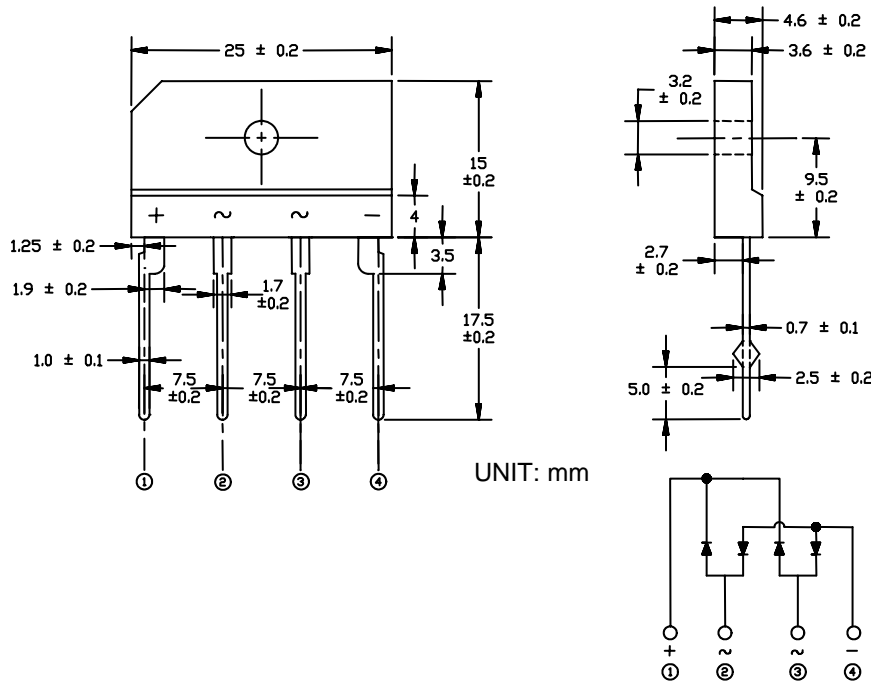
## 10-AMPERE SILICON BRIDGE RECTIFIER

### FEATURES

- Low Reverse Leakage Current
- Surge Overload Rating to 120A Peak
- Ideal for Printed Circuit Board Applications
- Epoxy Material – UL Recognition  
Flammability Classification 94V-0

### Mechanical Data

- Case: Molded Epoxy Resin
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Molded on Body



### Maximum Ratings & Characteristics

Single Phase, 60 Hz, Resistive or Inductive Load  
T<sub>a</sub> = 25°C Unless Otherwise Specified

| CHARACTERISTIC  | SYMBOL                            | T10XB40     | T10XB60 | T10XB80 | UNIT |
|---|-----------------------------------|-------------|---------|---------|------|
| Peak Repetitive Reverse Voltage   | V <sub>RRM</sub>                  | 400         | 600     | 800     | V    |
| RMS Reverse Voltage   | V <sub>R(RMS)</sub>               | 280         | 420     | 560     | V    |
| Average Rectified Output Current @ T <sub>c</sub> = 108°C w/ cooling fin                            | I <sub>o</sub>                    | 10.0        |         |         | A    |
| Average Rectified Output Current @ T <sub>a</sub> = 25°C w/o cooling fin                            | I <sub>o</sub>                    | 2.7         |         |         | A    |
| Non-Repetitive Peak Forward Surge Current<br>10 mS single half sine-wave superimposed on rated load | I <sub>FSM</sub>                  | 120         |         |         | A    |
| Maximum Forward Voltage per Element, I <sub>F</sub> = 5.0 A   | V <sub>F</sub>                    | 1.05        |         |         | V    |
| Peak Reverse Current per element at V <sub>R</sub> = V <sub>RRM</sub>                               | I <sub>R</sub>                    | 10          |         |         | μA   |
| Operating and Storage Temperature Range   | T <sub>J</sub> , T <sub>stg</sub> | -40 to +150 |         |         | °C   |

### Reference Table for Heat-Sink Size

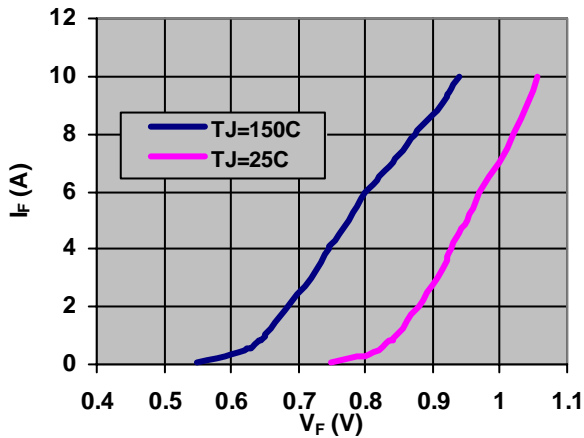
| Average Rectified Output Current in Amps           | 3.0 | 5.0 | 7.5 | 9   | 11  |
|--|-----|-----|-----|-----|-----|
| Cooling Fin Single-face Area S1 (cm <sup>2</sup> ) | 4   | 75  | 180 | 500 | 900 |
| Cooling Fin Single-face Area S2 (cm <sup>2</sup> ) | 8   | 65  | 100 | 310 | 490 |

Note: Vertical Mounting at T<sub>a</sub> = 40°C. HS Material: S1 = 1.5mm-Thick Aluminum, S2 = 3.0mm-Thick Copper  
Manufactured by Tianjin Zhong – Huan Semiconductor Co., Ltd.

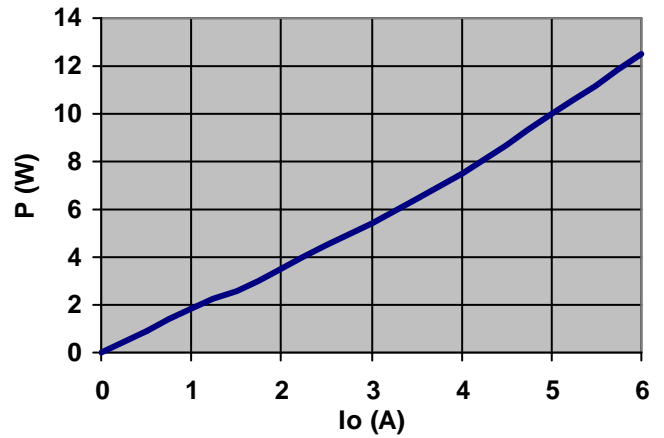
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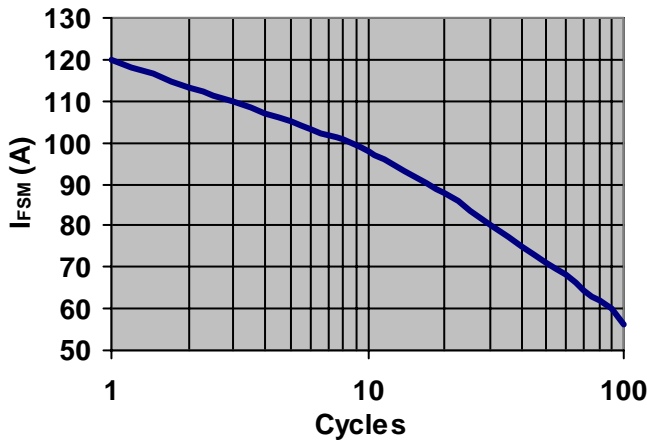
**Forward Voltage**



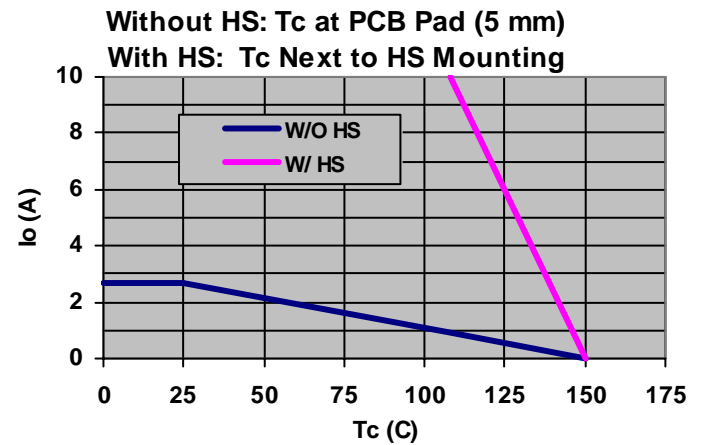
**P -  $I_o$  Curve**



**Surge Forward Current**



**Current Derating**



In order to avoid damaging devices, please observe the following precautions:

1. When using automated soldering equipment, use 60/40 (Sn/Pb) solder (melting point of  $180^\circ\text{C}$ ) with a neutral flux similar to rosin. Preheat time should be limited to 1 – 2 minutes at  $150^\circ\text{C}$ .
2. When using a soldering iron, use a tip temperature of less than  $300^\circ\text{C}$  (or a soldering iron power of less than 60W). Keep the soldering time below 5 seconds.
3. After soldering, remove any flux residue to avoid corrosion.
4. Because over-voltage or over-current testing may cause permanent damage to the devices, be sure to check the test equipment for proper voltage, current and ground connection prior to beginning the test.
5. If the devices are to be encapsulated, they should be cleaned and dried at  $120^\circ \pm 5^\circ\text{C}$  for at least 24 hours prior to encapsulation. Test for compatibility between the device package and the encapsulation material.